

Microstrip

Despite its structural simplicity, the microstrip line is difficult to analyze rigorously. However extensive research has provided numerous approximate modelling techniques which are adequate for many design purposes. The following are a collection of some of the more useful formulae for microstrip circuit design.

1 EQUATIONS FOR MICROSTRIP LINES

The following variables are used in the formulae below:

ϵ_r	substrate dielectric constant
h	substrate thickness
w	microstrip physical line width
Z_0	characteristic impedance
ϵ_{eff}	microstrip effective permittivity
l_{eo}	effective open-end length extension
w_{eff}	microstrip effective width

In the following, f is in GHz and h is in millimeters.

1.1 Static Microstrip Synthesis

Find the required w/h ratio given desired characteristic impedance and substrate parameters (see [1]-[2]). Valid for low frequencies.

$$\frac{w}{h} = \begin{cases} \left[\frac{\exp H'}{8} - \frac{1}{4 \exp H'} \right]^{-1} & Z_0 > (44 - 2\epsilon_r) \\ \frac{2}{\pi} [d_\epsilon - \ln(2d_\epsilon + 1)] + \frac{\epsilon_r - 1}{\pi \epsilon_r} (\ln d_\epsilon + 0.293 - 0.517/\epsilon_r) & Z_0 < (44 - 2\epsilon_r) \end{cases} \quad (1)$$

$$\text{where} \quad H' = \frac{Z_0 \sqrt{2(\epsilon_r + 1)}}{119.9} + \frac{1}{2} \left(\frac{\epsilon_r - 1}{\epsilon_r + 1} \right) \left(\ln \frac{\pi}{2} + \frac{1}{\epsilon_r} \ln \frac{4}{\pi} \right)$$
$$d_\epsilon = \frac{59.95\pi^2}{Z_0 \sqrt{\epsilon_r}}$$

1.2 Static Microstrip Analysis

Find the low-frequency characteristic impedance given the physical dimensions of the line (see [1]-[2]):

$$Z_0(0) = \begin{cases} \frac{119.9}{\sqrt{2(\epsilon_r + 1)}} \left[\ln \left(4h/w + \sqrt{16(h/w)^2 + 2} \right) \right. & w/h < 3.3 \\ \left. - \frac{1}{2} \left(\frac{\epsilon_r - 1}{\epsilon_r + 1} \right) \left(\ln \frac{\pi}{2} + \frac{1}{\epsilon_r} \ln \frac{4}{\pi} \right) \right] & \\ \frac{119.9\pi}{2\sqrt{\epsilon}} \left\{ \frac{w}{2h} + \frac{\ln 4}{\pi} + \frac{\ln(e\pi^2/16)}{2\pi} \left(\frac{\epsilon_r - 1}{\epsilon_r^2} \right) \right. & w/h > 3.3 \\ \left. + \frac{\epsilon_r + 1}{2\pi\epsilon_r} \left[\ln \frac{\pi e}{2} + \ln \left(\frac{w}{2h} + 0.94 \right) \right] \right\}^{-1} & \end{cases} \quad (2)$$

1.3 Static Effective Permittivity

Find the low-frequency effective permittivity given either electrical or physical characteristic of the microstrip (see [1]-[2]):

$$\epsilon_{eff}(0) = \begin{cases} \frac{\epsilon_r + 1}{2} \left[1 - \frac{1}{2H'} \left(\frac{\epsilon_r - 1}{\epsilon_r + 1} \right) \left(\ln \frac{\pi}{2} + \frac{1}{\epsilon_r} \ln \frac{4}{\pi} \right) \right]^{-2} & w/h < 1.3 \\ \frac{\epsilon_r + 1}{2} + \frac{\epsilon_r - 1}{2} \left(1 + 10 \frac{h}{w} \right)^{-0.555} & w/h > 1.3 \end{cases} \quad (3)$$

where H' is defined as in (1), or equivalently as a function of w/h given by

$$H' = \ln \left(4h/w + \sqrt{16(h/w)^2 + 2} \right)$$

1.4 Effective Permittivity Dispersion

Gives frequency-dependent effective permittivity, obtained by curve-fitting to rigorous analytical results (see [7]):

$$\epsilon_{eff}(f) = \epsilon_r - \frac{\epsilon_r - \epsilon_{eff}(0)}{1 + P(f)} \quad (4)$$

$$\begin{aligned} \text{where } P(f) &= P_1 P_2 [(0.1844 + P_3 P_4) 10fh]^{1.5763} \\ P_1 &= 0.27488 + [0.6315 + 0.525/(1 + 0.157fh)^{20}]w/h \\ &\quad - 0.065683 \exp(-8.7513w/h) \\ P_2 &= 0.33622[1 - \exp(-0.03442\epsilon_r)] \\ P_3 &= 0.0363 \exp(-4.6w/h) \{1 - \exp[-(fh/3.87)^{4.97}]\} \\ P_4 &= 1 + 2.751 \{1 - \exp[-(\epsilon_r/15.916)^8]\} \end{aligned}$$

with a 0.6% accuracy over the ranges $0.1 \leq w/h \leq 100$, $1 \leq \epsilon_r \leq 20$, $0 \leq h/\lambda_0 \leq 0.13$, and $\epsilon_{eff}(0)$ is calculated from (3).

1.5 Impedance Dispersion

Gives frequency-dependent characteristic impedance, obtained by curve-fitting to rigorous analytical results, using the power-current definition for impedance (see [2]):

$$Z_0(f) = Z_0(0) (R_8/R_9)^{R_{12}} \quad (5)$$

where

$$\begin{aligned} R_1 &= 4.766 \exp[-3.228 (w/h)^{0.641}] \\ R_2 &= 0.016 + (0.0514 \epsilon_r)^{4.524} \\ R_3 &= 1.206 - 0.3144 \exp(-0.0389 \epsilon_r^{1.4}) [1 - \exp(-0.267 (w/h)^7)] \\ R_4 &= 1 + 1.275 [1 - \exp(-0.00463 R_1 \epsilon_r^{1.674} (hf/18.37)^{2.745})] \\ R_5 &= \frac{5.086 R_2 (hf/28.84)^{12} \exp[-22.2 (w/h)^{1.92}]}{0.384 + 0.386 R_2} \frac{\exp[-22.2 (w/h)^{1.92}]}{1 + 1.3 (hf/28.84)^{12}} \frac{(\epsilon_r - 1)^6}{1 + 10(\epsilon_r - 1)^6} \\ R_6 &= [0.0962 + (19.47/hf)^6]^{-1} \\ R_7 &= [1 + 0.00245 (w/h)^2]^{-1} \\ R_8 &= 0.9408 \epsilon_{\text{eff}}^{R_4}(f) - 0.9603 \\ R_9 &= (0.9408 - R_5) \epsilon_{\text{eff}}^{R_4}(0) - 0.9603 \\ R_{10} &= 0.707 (0.00044 \epsilon_r^{2.136} + 0.0184) (hf/12.3)^{1.097} \\ R_{11} &= 1 + 0.0503 \epsilon_r^2 R_6 \{1 - \exp[-(w/15h)^6]\} \\ R_{12} &= R_3 \{1 - 1.1241 (R_7/R_{11}) \exp[-0.026(hf)^{1.1566} - R_{10}]\} \end{aligned}$$

The accuracy is specified to less than 1% for the ranges $0.1 \leq w/h \leq 10$, $1 \leq \epsilon_r \leq 18$, and $0 \leq h \cdot f \leq 30$ GHz·mm.

1.6 Microstrip Effective Width

The planar-waveguide model (see [3]) replaces a microstrip of width w by an ideal parallel-plane transmission line of width w_{eff} , where

$$w_{eff}(f) = \frac{h\eta_0}{Z(f)\sqrt{\epsilon_{\text{eff}}(f)}} \quad (6)$$

and where $Z(f)$ and $\epsilon_{eff}(f)$ are calculated using the models described in (4) and (5)

1.7 Open-End Length Correction

Gives the effective length extension due to fringing at microstrip open circuits (see [5]-[6]):

$$\frac{l_{eo}}{h} = \frac{1}{2\pi} \frac{w/h + 0.366}{w/h + 0.556} \left\{ 0.28 + \frac{\epsilon_r + 1}{\epsilon_r} [0.274 + \ln(w/h + 2.518)] \right\} \quad (7)$$

This is a static result from Hammerstad [5], and as noted by Leir [8] is valid for the extremely wide lines sometimes used for patch antennas, unlike a previous expression from Hammerstad [4].

If wide lines are not being used, the more accurate and frequency-dependent expression due to Jansen *et al.* [6] should be used, which is given by

$$\frac{l_{eo}}{h} = R_1 R_3 R_5 / R_4 \quad (8)$$

$$\begin{aligned} \text{where } R_1 &= 0.434907 \frac{\epsilon_{\text{eff}}^{0.81} + 0.26}{\epsilon_{\text{eff}}^{0.81} - 0.189} \frac{(w/h)^{0.8544} + 0.236}{(w/h)^{0.8544} + 0.87} \\ R_2 &= 1 + \frac{(w/h)^{0.371}}{2.358\epsilon_r + 1} \\ R_3 &= 1 + \frac{0.5274 \tan^{-1} [0.084(w/h)^{1.9413/R_2}]}{\epsilon_{\text{eff}}^{0.9236}} \\ R_4 &= 1 + 0.0377 \tan^{-1} [0.067(w/h)^{1.456}] \\ &\quad \times \{6 - 5 \exp [0.036(1 - \epsilon_r)]\} \\ R_5 &= 1 - 0.218 \exp(-7.5w/h) \end{aligned}$$

with a quoted accuracy of 2.5% over the range $0.01 \leq w/h \leq 100$ and $\epsilon_r < 50$. The effective dielectric constant $\epsilon_{eff}(f)$ should be calculated using the formula in (4).

1.8 Fringing Capacitance

The fringing capacitance of an open-circuited microstrip line is calculated from the open-end length extension as (see [1]-[2])

$$C_{\text{fringe}} \approx \frac{l_{eo} \sqrt{\epsilon_{eff}}}{cZ_0} \quad (9)$$

References

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